



# PJD16N06A

## 60V N-Channel Enhancement Mode MOSFET

**Voltage**

**60 V**

**Current**

**16 A**

### Features

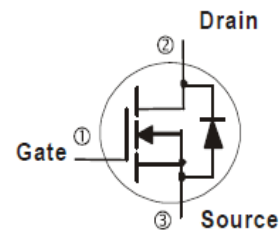
- $R_{DS(ON)}$ ,  $V_{GS}@10V, I_D@8A < 50m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V, I_D@4A < 60m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0104 ounces, 0.297grams



TO-252AA



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	$T_C=25^\circ\text{C}$	16
		$T_C=100^\circ\text{C}$	10
Pulsed Drain Current <sup>(Note 1)</sup>	$I_{DM}$	64	A
Power Dissipation	$P_D$	$T_C=25^\circ\text{C}$	27
		$T_C=100^\circ\text{C}$	10.8
Continuous Drain Current	$I_D$	$T_A=25^\circ\text{C}$	4.4
		$T_A=70^\circ\text{C}$	3.5
Power Dissipation	$P_D$	2.0	W
Power Dissipation	$P_D$	1.3	W
Single Pulse Avalanche Energy <sup>(Note 6)</sup>	$E_{AS}$	11	mJ
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{\theta JC}$	4.6
	Junction to Ambient	$R_{\theta JA}$	62.5

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1.0	1.77	2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =8A	-	37	50	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =4A	-	42	60	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	-	-	1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
<b>Dynamic</b> (Note 7)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =30V, I <sub>D</sub> =4A, V <sub>GS</sub> =10V (Note 1,2)	-	14	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	2.9	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	2.3	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	815	-	pF
Output Capacitance	C <sub>oss</sub>		-	379	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	110	-	
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =30V, I <sub>D</sub> =1A, V <sub>GS</sub> =10V, R <sub>G</sub> =3.3Ω (Note 1,2)	-	3.9	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	13	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	23	-	
Turn-Off Fall Time	t <sub>f</sub>		-	6.7	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	---	-	-	16	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.73	1.0	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T<sub>J</sub>(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> = 25°C.
4. The maximum current rating is package limited.
5. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz. square pad of copper.
6. The test condition is L=0.1mH, I<sub>AS</sub>=15A, V<sub>DD</sub>=25V, V<sub>GS</sub>=10V
7. Guaranteed by design, not subject to production testing.



# PJD16N06A

## TYPICAL CHARACTERISTIC CURVES

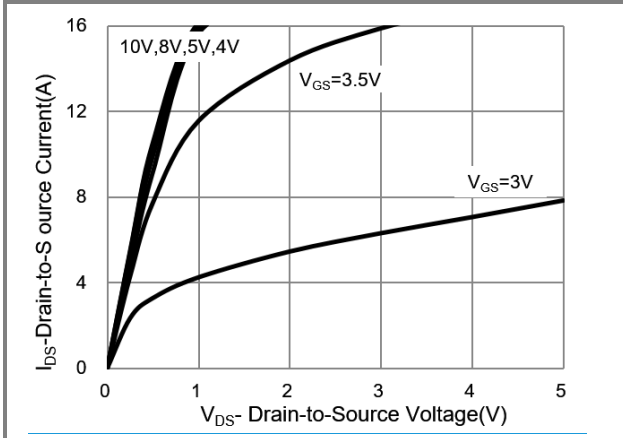


Fig.1 Output Characteristics

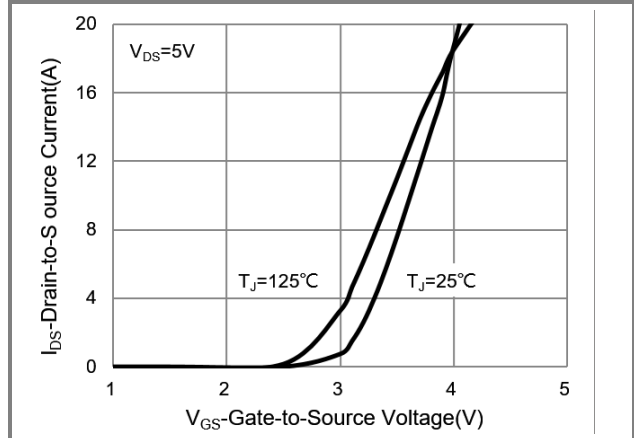


Fig.2 Transfer Characteristics

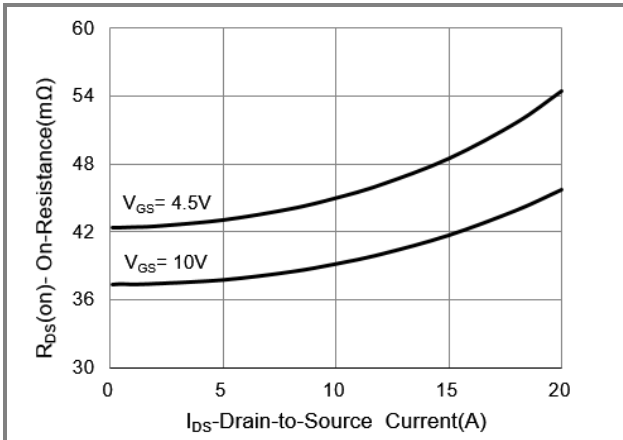


Fig.3 On-Resistance vs. Drain Current

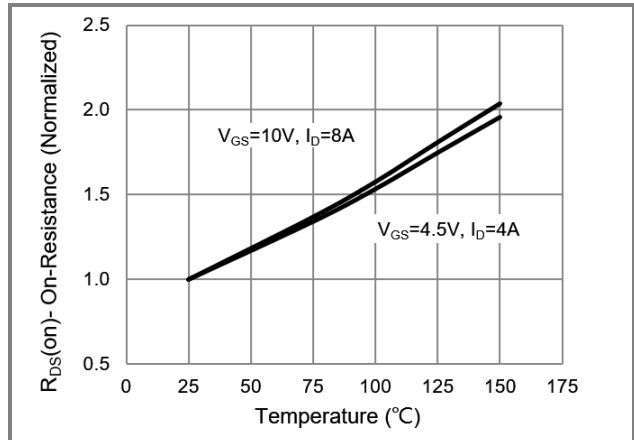


Fig.4 On-Resistance vs. Junction temperature

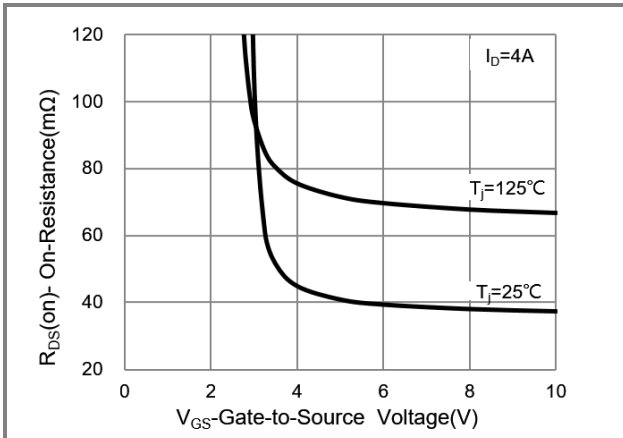


Fig.5 On-Resistance Variation with VGS.

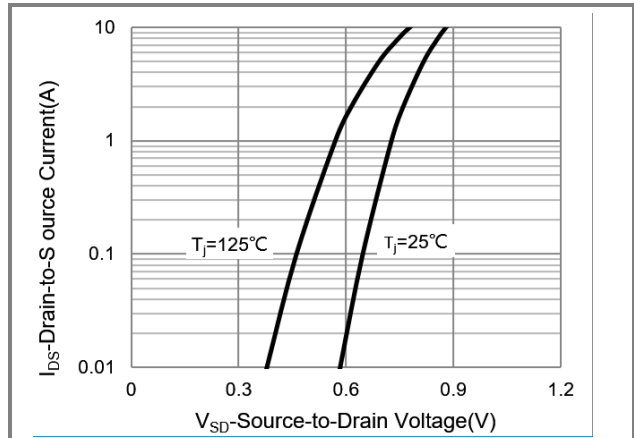


Fig.6 Source-Drain Diode Forward Voltage



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## TYPICAL CHARACTERISTIC CURVES

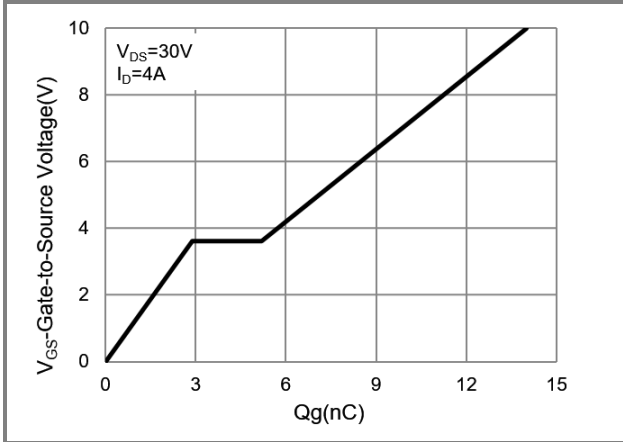


Fig.7 Gate-Charge Characteristics

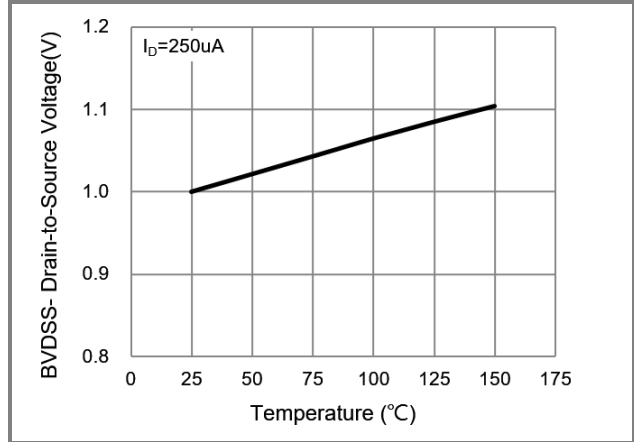


Fig.8 Breakdown Voltage Variation vs. Temperature

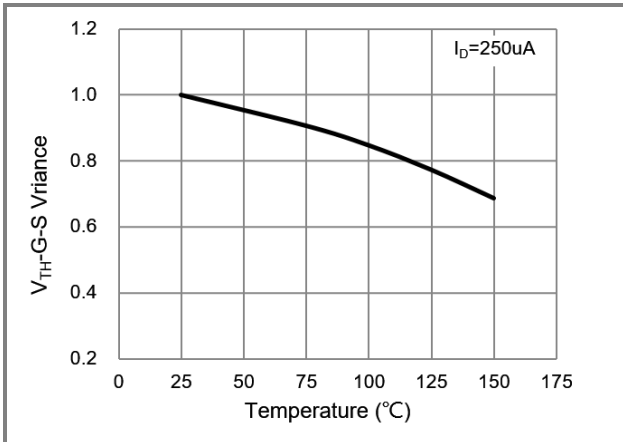


Fig.9 Threshold Voltage Variation with Temperature

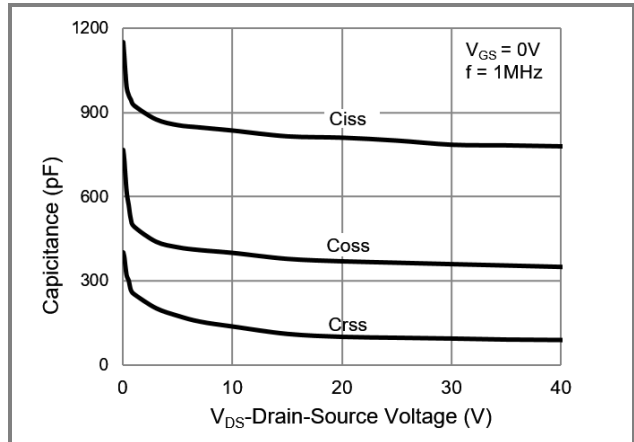


Fig.10 Capacitance vs. Drain-Source Voltage

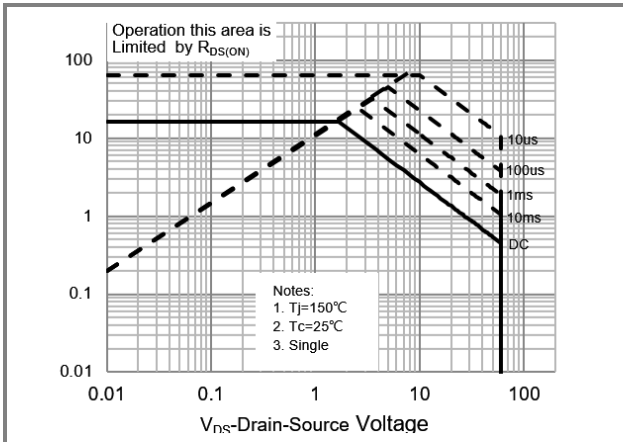


Fig.11 Maximum Safe Operating Area



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## TYPICAL CHARACTERISTIC CURVES

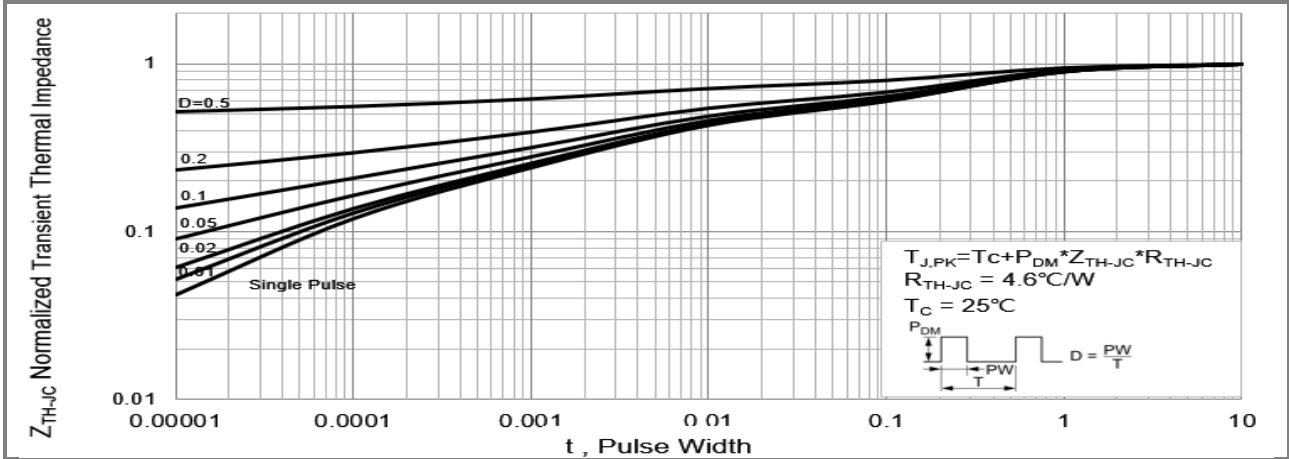
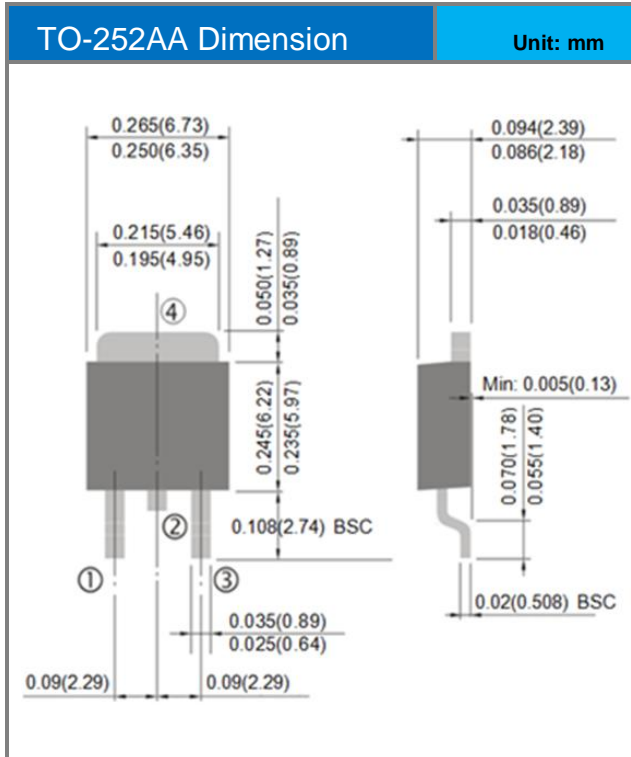


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width



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## Packaging Information



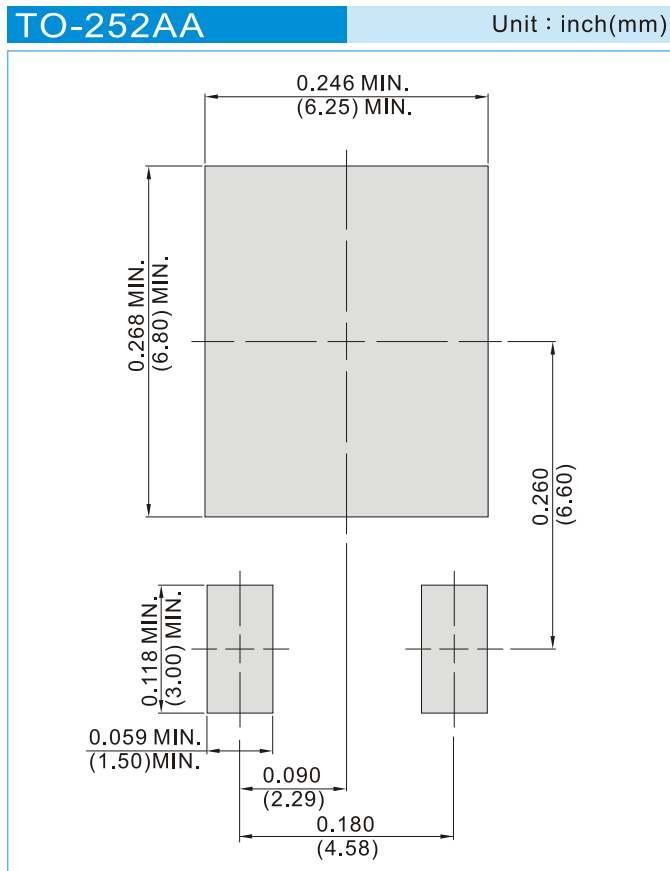


# PJD16N06A

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD16N06A_L2_00001	TO-252AA	3,000pcs / 13" reel	D16N06A	Halogen free

## MOUNTING PAD LAYOUT





## PJD16N06A

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